

FEATURES

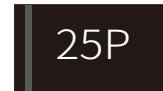
- Protects one data line
- Low reverse current: <math><10\text{nA}</math> typical ($V_R = 2.5\text{V}</math>)$
- Working voltage: 2.5 V
- Low leakage current
- Solid-state silicon-avalanche technology

APPLICATIONS

- Cellular Handsets & Accessories
- Portable Instrumentation
- Notebooks & Desktop Computers
- Internet of Things (IOT) Devices



DFN1006



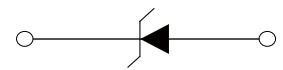
Marking

IEC COMPATIBILITY

- IEC61000-4-2 (ESD) $\pm 20\text{kV}$ (air), $\pm 15\text{kV}$ (contact)
- IEC61000-4-4 (EFT) 40A (5/50ns)

APPROVALS

- RoHS** Compliance with 2011/65/EU
- HF** Compliance with IEC61249-2-21:2003



Schematic Symbol

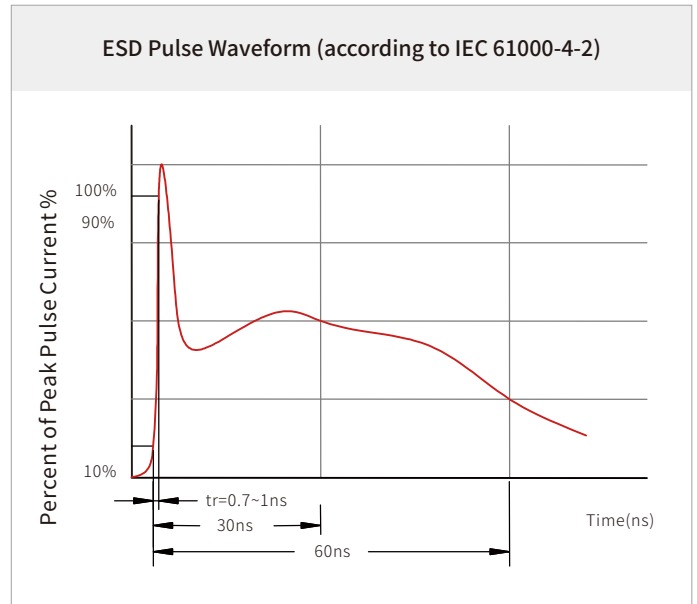
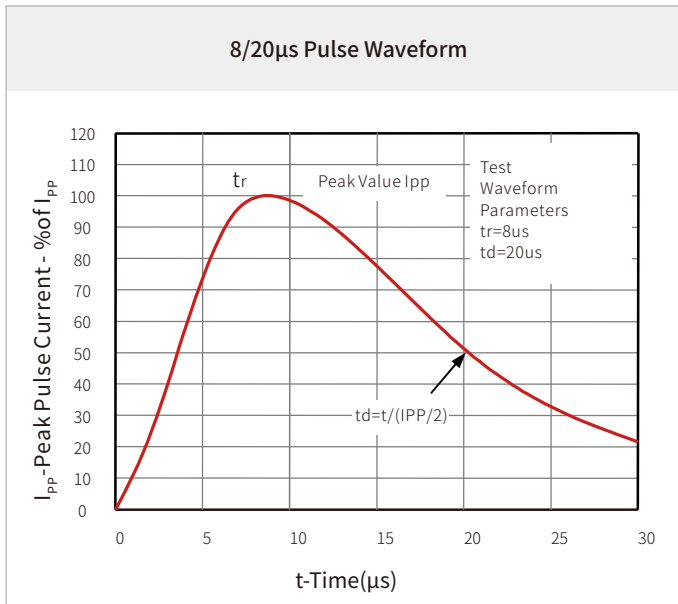
THERMAL CONSIDERATIONS

Symbol	Parameter	Value	Unit
P_{PP}	Peak Pulse Power (tp=8/20 μ s waveform)	35	Watts
T_J	Operating Temperature Range	-55 to +150	$^{\circ}\text{C}$
T_{STG}	Storage Temperature Range	-55 to +150	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS

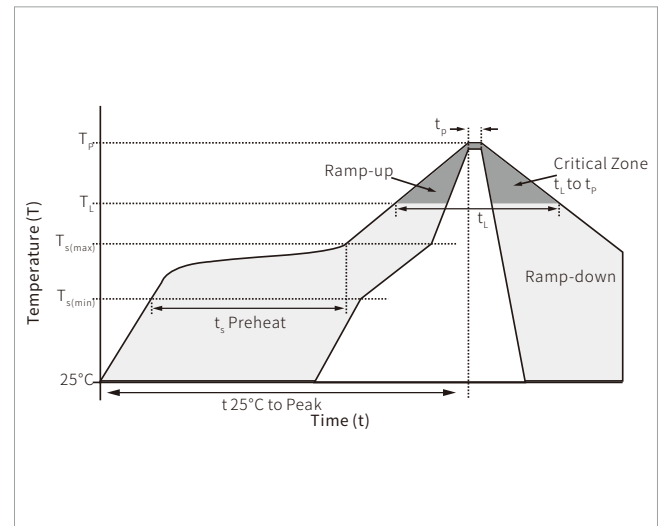
Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
V_{RWM}	Reverse Stand-off Voltage				2.5	V
V_{BR}	Reverse Breakdown Voltage	$I_T = 1\text{mA}$	3.0	3.5	4.5	V
I_R	Reverse Leakage Current	$V_{RWM} = 2.5\text{V}$			0.05	μA
V_C	Clamping Voltage	$I_{PP} = 1\text{A}, tp = 8/20\mu\text{s}$			5	V
V_C	Clamping Voltage	$I_{PP} = 5\text{A}, tp = 8/20\mu\text{s}$			7.5	V
I_{PP}	Peak Pulse Current	tp=8/20 μ s			5	A
V_F	Forward Voltage	$I_F = -10\text{mA}$			1.2	A
C_J	Off State Junction Capacitance	$V_R = 0\text{V}, f = 1\text{MHz}$			30	pF

CHARACTERISTIC CURVES

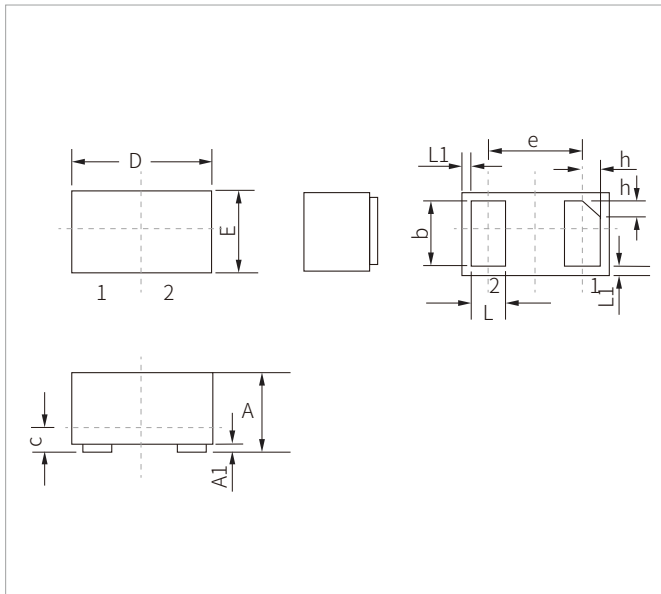


SOLDERING PARAMETERS

Reflow Condition		Lead-free assembly
Pre Heat	Temperature Max ($T_{s(min)}$)	150°C
	Temperature Max ($T_{s(max)}$)	200°C
	Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus Temp (T_L) to peak)		3°C/second max
$T_{s(max)}$ to T_L - Ramp-up Rate		3°C/second max
Reflow	Temperature (T_L) (Liquidus)	217°C
	Time (min to max) (t_L)	60 – 150 seconds
Peak Temperature (T_p)		260°C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes max.
Do not exceed		260°C

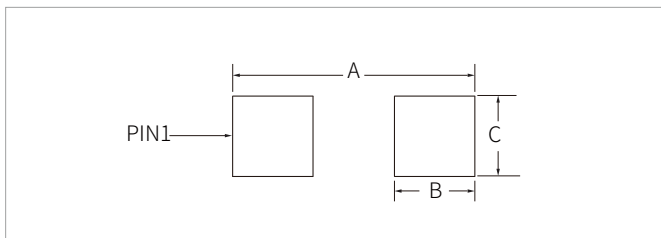


DFN1006 PACKAGE INFORMATION



Ref.	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	0.40	0.60	0.016	0.024
A1	0	0.05	0	0.002
b	0.40	0.55	0.016	0.022
c	0.12	0.18	0.005	0.007
D	0.90	1.10	0.035	0.043
e	0.65BSC		0.026BSC	
E	0.55	0.75	0.022	0.030
L	0.20	0.35	0.008	0.014
L1	0.05REF		0.002REF	
h	0.07	0.17	0.003	0.007

RECOMMENDED PAD LAYOUT DIMENSIONS



Ref.	Millimeters	Inches
A	1.20	0.047
B	0.47	0.019
C	0.60	0.024

ORDERING INFORMATION

Part Number	Component Package	QTY/Reel	Reel Size
SE10F04U2.5A	DFN1006	10000PCS	7"

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